

# **HD74LV4066A**

## Quad. Analog Switches / Quad. Multiplexers

REJ03D0340-0400Z (Previous ADE-205-285B (Z)) Rev.4.00 Jul. 21, 2004

### **Description**

The HD74LV4066A handles both analog and digital signals, and enables signals of either type with amplitudes of up to 5.5 V (peak) to be transmitted in either direction (at  $V_{CC} = 0$  V to 5.5 V).

Each switch section has its own enable input control (C). A high-level voltage applied to C turns on the associated switch section.

Applications include signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog-to-digital and digital-to-analog conversion systems.

#### **Features**

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V operation}$
- All control inputs  $V_{IH}$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV4066AFPEL	SOP-14 pin (JEITA)	FP-14DAV	FP	EL (2,000 pcs/reel)
HD74LV4066ARPEL	SOP-14 pin (JEDEC)	FP-14DNV	RP	EL (2,500 pcs/reel)
HD74LV4066ATELL	TSSOP-14 pin	TTP-14DV	Т	ELL (2,000 pcs/reel)

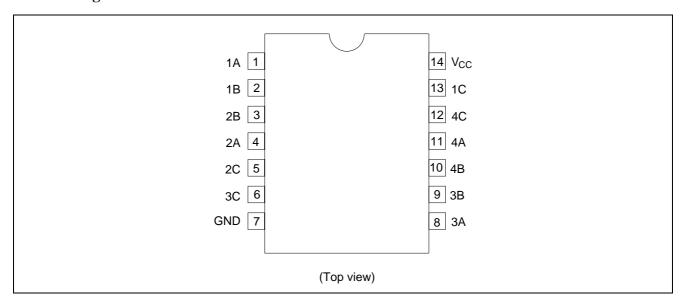
Note: Please consult the sales office for the above package availability.

#### **Function Table**

Control	Switch
L	OFF
Н	ON

Note: H: High level L: Low level

### **Pin Arrangement**



### **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	$V_{CC}$	-0.5 to 7.0	V	
Input voltage range*1	Vı	-0.5 to 7.0	V	
Output voltage range*1, 2	Vo	$-0.5$ to $V_{CC}$ + 0.5	V	Output: H or L
Input clamp current	I <sub>IK</sub>	-20	mA	V <sub>I</sub> < 0
Output clamp current	lok	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	I <sub>O</sub>	±25	mA	$V_O = 0$ to $V_{CC}$
Continuous current through V <sub>CC</sub> or GND	I <sub>CC</sub> or I <sub>GND</sub>	±50	mA	
Maximum power dissipation at	P <sub>T</sub>	785	mW	SOP
Ta = $25^{\circ}$ C (in still air)* <sup>3</sup>		500		TSSOP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded even if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

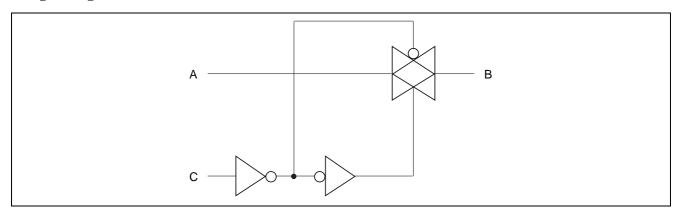
## **Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	Vcc	2.0* <sup>1</sup>	5.5	V	
Input voltage range	Vı	0	5.5	V	
Output voltage range	V <sub>I/O</sub>	0	V <sub>CC</sub>	V	
Input transition rise or fall rate	Δt/Δν	0	200	ns/V	V <sub>CC</sub> = 2.3 to 2.7 V
		0	100		V <sub>CC</sub> = 3.0 to 3.6 V
		0	20		V <sub>CC</sub> = 4.5 to 5.5 V
Operating free-air temperature	Та	-40	85	°C	

Notes: Unused or floating control inputs must be held high or low.

1. With the supply voltage at or around 2 V, the analog switch on-state resistance loses linearity significantly. It is recommended that only digital signals be transmitted at these low supply voltages.

## Logic Diagram



## **DC Electrical Characteristics**

			Ta =	25°C		Ta = -40 t	o 85°C			
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	<b>Test Conditions</b>	
Input voltage	V <sub>IH</sub>	2.0	_	_	_	1.5	_	V	Control input only	
		2.3 to 2.7	_	_	_	$V_{CC} \times 0.7$	_			
		3.0 to 3.6	_	_	_	$V_{CC} \times 0.7$	_			
		4.5 to 5.5	_	_	_	$V_{CC} \times 0.7$	_			
	V <sub>IL</sub>	2.0	_	_	_	_	0.5			
		2.3 to 2.7	_	_	_	_	$V_{CC} \times 0.3$			
		3.0 to 3.6	_	_	_	_	$V_{CC}\!\times\!0.3$			
		4.5 to 5.5	_	_	_	_	$V_{CC} \times 0.3$			
On-state switch	Ron	2.3	_	60	180	_	225	Ω	$V_{IN} = V_{CC}$ or GND	
resistance		3.0	_	50	150	_	190		$V_C = V_{IH}$	
		4.5	_	40	75	_	100		$I_T = 1 \text{ mA}$	
Peak on resistance	R <sub>ON (P)</sub>	2.3	_	250	500	_	600	Ω	$V_{IN} = V_{CC}$ to GND	
		3.0	_	100	180	_	225		$V_C = V_{IH}$	
		4.5	_	50	100	_	125		$I_T = 1 \text{ mA}$	
Difference of on-state	$\Delta R_{ON}$	2.3	_	20	30	_	40	Ω	V <sub>IN</sub> = V <sub>CC</sub> to GND	
resistance between		3.0	_	10	20	_	30		$V_C = V_{IH}$	
switches		4.5	_	7	15	_	20		$I_T = 1 \text{ mA}$	
Off-state switch leakage current	Is (OFF)	5.5	_	_	±0.1	_	±1.0	μА	$\begin{aligned} &V_{IN} = V_{CC}, \\ &V_{OUT} = GND \text{ or } \\ &V_{IN} = GND, \\ &V_{O} = V_{CC}, \ V_{C} = V_{IL} \end{aligned}$	
On-state switch leakage current	Is (ON)	5.5	_	_	±0.1	_	±1.0	μΑ	$V_{IN} = V_{CC}$ or GND $V_C = V_{IH}$	
Input current	I <sub>IN</sub>	0 to 5.5	_	_	±0.1	_	±1.0	μΑ	$V_{IN} = 5.5 \text{ V or GND}$	
Quiescent supply current	Icc	5.5	_	_	_	_	20	μΑ	$V_{IN} = V_{CC}$ or GND	

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

## **Switching Characteristics**

 $V_{CC}=2.5\pm0.2~V$ 

		Ta = :	25°C	$Ta = -40 \text{ to } 85^{\circ}C$					FROM	ТО	
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Test Cond	ditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	2.0	10.0	_	16.0	ns	C <sub>L</sub> = 15 pF	=	A or B	B or A
delay time	t <sub>PHL</sub>	_	5.0	12.0	_	18.0	=	$C_{L} = 50 \text{ pF}$	-	_	
Enable time	t <sub>ZH</sub>	_	6.0	15.0	_	20.0	ns	$R_L = 1 k\Omega$	C <sub>L</sub> = 15 pF	С	A or B
	$t_{ZL}$	_	8.0	25.0	_	32.0	_		C <sub>L</sub> = 50 pF	_	
Disable time	t <sub>HZ</sub>	_	7.0	15.0	_	23.0	ns	$R_L = 1 k\Omega$	C <sub>L</sub> = 15 pF	С	A or B
	$t_{LZ}$	_	11.0	25.0	_	32.0	_		C <sub>L</sub> = 50 pF	_	

 $V_{CC} = 3.3 \pm 0.3 \ V$ 

		Ta =	25°C	$Ta = -40 \text{ to } 85^{\circ}C$					FROM	TO	
ltem	Symbol	Min	Тур	Max	Min	Max	Unit	Jnit Test Conditions		(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	1.5	6.0	_	10.0	ns	C <sub>L</sub> = 15 pF	=	A or B	B or A
delay time	t <sub>PHL</sub>	_	4.0	9.0	_	12.0	_	$C_{L} = 50 \text{ pf}$	=	_	
Enable time	t <sub>zH</sub>	_	4.0	11.0	_	15.0	ns	$R_L = 1 k\Omega$	C <sub>L</sub> = 15 pF	С	A or B
	$t_{ZL}$	_	6.0	18.0	_	22.0	_		C <sub>L</sub> = 50 pF	_	
Disable time	t <sub>HZ</sub>	_	5.0	11.0	_	15.0	ns	$R_L = 1 k\Omega$	C <sub>L</sub> = 15 pF	С	A or B
	$t_{LZ}$	_	8.0	18.0	_	22.0	_		C <sub>L</sub> = 50 pF	_	

 $V_{CC}=5.0\pm0.5~V$ 

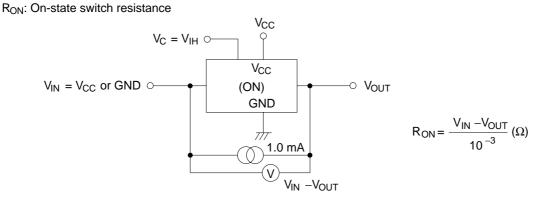
		Ta = :	25°C	Ta = -40 to 85°C					FROM	то	
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Test Condit	ions	(Input)	(Output)
Propagation	t <sub>PLH</sub>		1.0	4.0	_	7.0	ns	$C_L = 15  pF$		A or B	B or A
delay time	t <sub>PHL</sub>	_	3.0	6.0	_	8.0	=	$C_L = 50 pF$		_	
Enable time	t <sub>zH</sub>	_	3.0	7.0	_	10.0	ns	$R_L = 1 k\Omega$	C <sub>L</sub> = 15 pF	С	A or B
	$t_{ZL}$	_	5.0	12.0		16.0		C	C <sub>L</sub> = 50 pF		
Disable time	t <sub>HZ</sub>	_	4.0	7.0		10.0	ns	$R_L = 1 k\Omega$	C <sub>L</sub> = 15 pF	С	A or B
	$t_{LZ}$	_	6.0	12.0	_	16.0		C	C <sub>L</sub> = 50 pF		

## **Switching Characteristics (Cont.)**

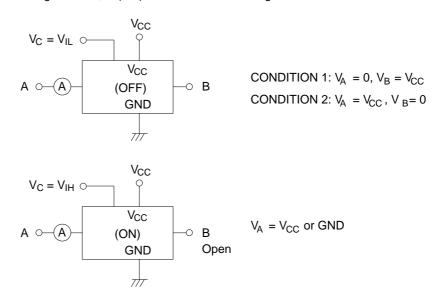
			Ta =	25°C				FROM	то
Item	Symbol	V <sub>CC</sub> (V)	Min	Тур	Max	Unit	Test Conditions	(Input)	(Output)
Control input capacitance	C <sub>IC</sub>	_	_	3.5	_	pF			
Switch terminal capacitance	C <sub>I/O</sub>	_	_	6.0	_	pF			
Feedthrough capacitance	Ст	_	_	0.5	_	pF			
Power dissipation capacitance	$C_{PD}$	_	_	4.0	_	pF			
Frequency		2.3	_	30.0	_	MHz	$C_L = 50 \text{ pF}, R_L = 600 \Omega$	A or B	B or A
response (Switch ON)		3.0	_	35.0	_	_	Adjust f <sub>in</sub> voltage to obtain 0 dBm at output when f <sub>in</sub> is 1 MHz (sine		
(SWILCH ON)		4.5	_	50.0	_		wave). Increase f <sub>in</sub> frequency until		
							the dB-meter reads $-3$ dBm. 20 log (V <sub>O</sub> /V <sub>I</sub> ) = $-3$ dBm		
Crosstalk		2.3		-45.0		dB	$C_L = 50 \text{ pF}, R_L = 600 \Omega$	A or B	B or A
(Between any		3.0	_	-45.0		_	Adjust f <sub>in</sub> voltage to obtain 0 dBm		
switches)		4.5	_	-45.0	_		at input when $f_{in}$ is 1 MHz (sine wave).		
Crosstalk		2.3	_	15.0	_	_ mV	$C_L = 50 \text{ pF}, R_L = 600 \Omega$	С	A or B
(Control input to signal		3.0	_	20.0		_	Adjust $R_L$ value to obtain 0 A at $I_{IN/OUT}$ when $f_{in}$ is		
output)		4.5	_	50.0	_		1 MHz (square wave).		
Feedthrough		2.3	_	-40.0	_	dB	$C_L = 50 \text{ pF}, R_L = 600 \Omega$	A or B	B or A
attenuation		3.0	_	-40.0		_	Adjust fin voltage to obtain 0 dBm at		
(Switch OFF)		4.5	_	-40.0	_		input when f <sub>in</sub> is 1 MHz (sine wave).		
Sine-wave		2.3		0.1	_	_ %	$C_L = 50 \text{ pF}, R_L = 10 \text{ k}\Omega$	A or B	B or A
distortion		3.0	_	0.1	_	_	$f_{IN} = 1 \text{ kHz (sine wave)}$ $V_I = 2 V_{P-P}, V_{CC} = 2.3 \text{ V}$		
		4.5	_	0.1	_		$V_1 = 2 \text{ Vp.p., } V_{CC} = 2.3 \text{ V}$ $V_1 = 2.5 \text{ Vp.p., } V_{CC} = 3.0 \text{ V}$ $V_1 = 4 \text{ Vp.p., } V_{CC} = 4.5 \text{ V}$		

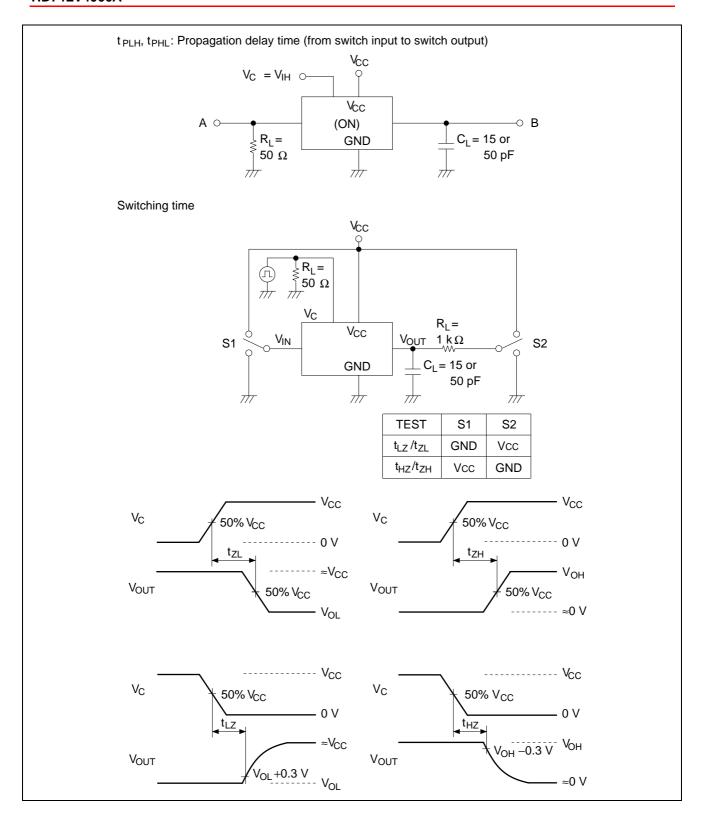
#### **Test Circuits**

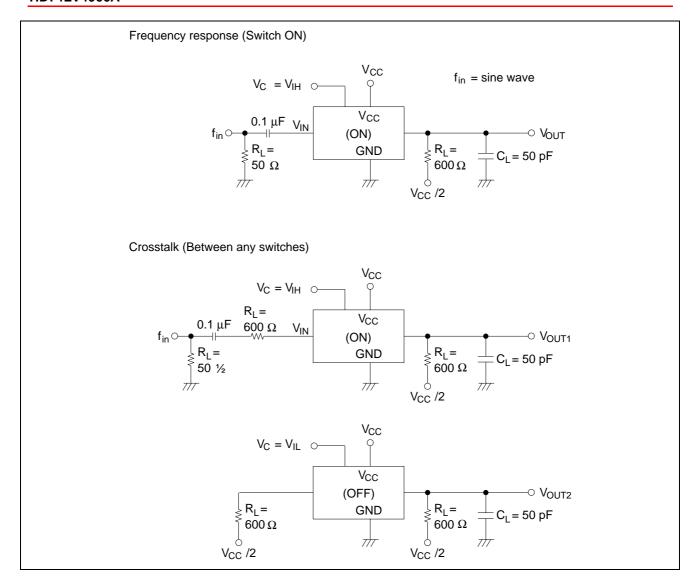




Is (OFF): Off-state switch leakage current, Is (ON): On-state switch leakage current

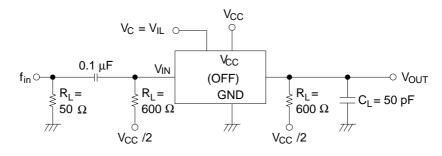




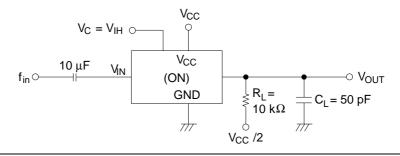


# Crosstalk (Control input to signal output) $V_{CC}$ GND $\overline{600}\,\Omega$ 1//

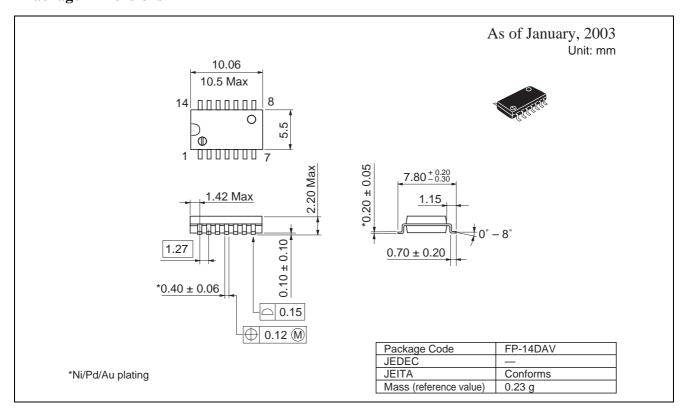
Feedthrough attenuation (Switch OFF)

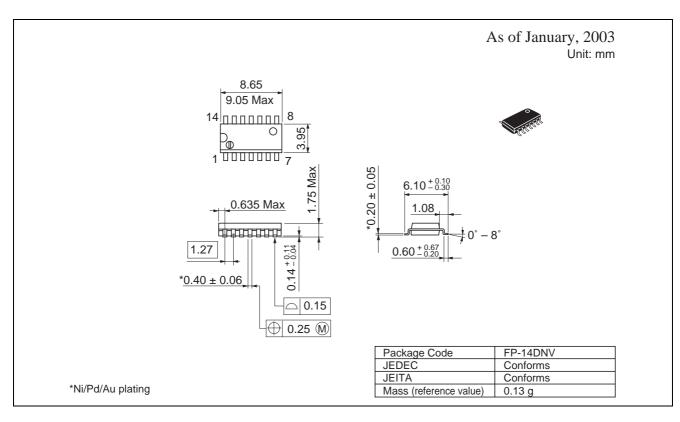


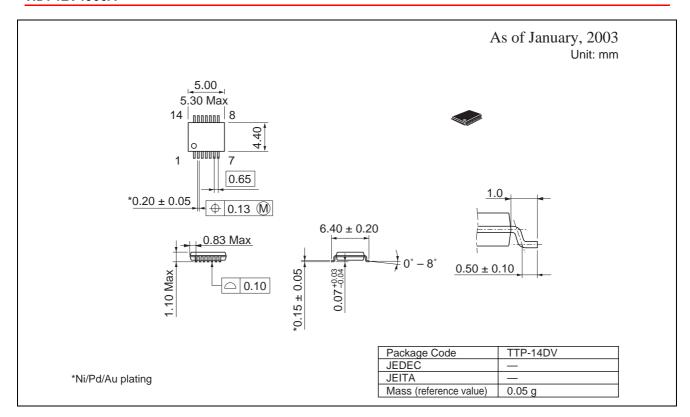
Sine-wave distortion



## **Package Dimensions**







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